

100V N-Channel Enhancement Mode MOSFET

Voltage	100 V	R _{DSON,max}	3.3 mΩ
Current	219 A	Q _{G (TYP)}	65 nC

Feature

- R_{DSON,max} < 3.3 mΩ at V_{GS} = 10 V, I_D = 64 A
- R_{DSON,max} < 4.7 mΩ at V_{GS} = 6 V, I_D = 32 A
- High switching speed
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

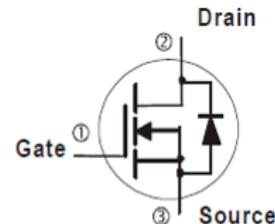
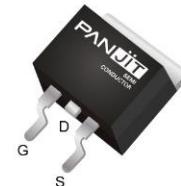
Mechanical Data

- Case: TO-263AB-L package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 1.4549 grams

Application

- BMS, SR of industrial PSU.

TO-263AB-L



Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current (Note 3)	I _D	219	A
T _C =25 °C		155	
T _C =100 °C			
Pulsed Drain Current (Note 6)	I _{DM}	876	A
T _C =25 °C			
Single Pulse Avalanche Current (Note 5)	I _{AS}	70	A
Single Pulse Avalanche Energy (Note 5)	E _{AS}	245	mJ
Power Dissipation	P _D	333	W
T _C =25 °C		166	
T _C =100 °C			
Operating Junction and Storage Temperature Range	T _{J,T_{STG}}	-55~175	°C

Thermal Characteristics

PARAMETER	SYMBOL	VALUES			UNITS
		MIN.	TYP.	MAX.	
Thermal Resistance	Junction-to-Case (Bottom)	R _{θJC}	-	0.3	°C/W
	Junction-to-Ambient (Note 4)	R _{θJA}	-	-	40 °C/W

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0 \text{ V}, I_{\text{D}}=250 \mu\text{A}$	100	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=440 \mu\text{A}$	1.8	2.8	3.8	
Drain-Source On-State Resistance (Note 1)	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10 \text{ V}, I_{\text{D}}=64 \text{ A}$	-	2.8	3.3	$\text{m}\Omega$
		$V_{\text{GS}}=6 \text{ V}, I_{\text{D}}=32 \text{ A}$	-	3.5	4.7	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=100 \text{ V}, V_{\text{GS}}=0 \text{ V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20 \text{ V}, V_{\text{DS}}=0 \text{ V}$	-	-	± 100	nA
Transfer characteristics (Note 1)	g_{fs}	$V_{\text{DS}}=10 \text{ V}, I_{\text{D}}=64 \text{ A}$	-	120	-	S
Dynamic Characteristics (Note 6)						
Total Gate Charge	Q_g	$V_{\text{DS}}=50 \text{ V}, I_{\text{D}}=64 \text{ A}, V_{\text{GS}}=10 \text{ V}$	-	65	85	nC
Gate-Source Charge	Q_{gs}		-	20	-	
Gate-Drain Charge	Q_{gd}		-	11	-	
Gate Plateau Voltage	V_{plateau}		-	4.5	-	V
Input Capacitance	C_{iss}	$V_{\text{DS}}=50 \text{ V}, V_{\text{GS}}=0 \text{ V}, f=250 \text{ kHz}$	-	4710	6120	pF
Output Capacitance	C_{oss}		-	1830	2380	
Reverse Transfer Capacitance	C_{rss}		-	21	-	
Output Charge	Q_{oss}	$V_{\text{DS}}=50 \text{ V}, V_{\text{GS}}=0 \text{ V}$	-	142	185	nC
Turn-On Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=50 \text{ V}, I_{\text{D}}=64 \text{ A}, V_{\text{GS}}=10 \text{ V}, R_{\text{G}}=1.6 \Omega$ (Note 2)	-	15.5	-	ns
Rise Time	t_r		-	4.9	-	
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	24.7	-	
Fall Time	t_f		-	4.9	-	
Gate Resistance	R_g	$f=1.0 \text{ MHz}$	-	0.35	0.7	Ω
Drain-Source Diode						
Diode Forward Voltage	V_{SD}	$I_s=64 \text{ A}, V_{\text{GS}}=0 \text{ V}$	-	0.9	1.2	V
Reverse Recovery Charge	Q_{rr}	$I_F=64 \text{ A}, V_{\text{DD}}=50 \text{ V},$ $\text{di}/\text{dt}=100 \text{ A}/\mu\text{s}$	-	192	-	nC
Reverse Recovery Time	T_{rr}		-	87	-	ns

NOTES :

1. Pulse width $\leq 300 \mu\text{s}$, Duty cycle $\leq 2 \%$.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum drain current calculated by maximum junction temperature and thermal impedance. It can be varied by application and environment.
4. $R_{\theta\text{JA}}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. E_{AS} is calculated based on the condition of $L = 0.1 \text{ mH}, I_{\text{AS}} = 70 \text{ A}, V_{\text{DD}} = 50 \text{ V}, V_{\text{GS}} = 10 \text{ V}$. 100% test in production.
6. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTIC CURVES

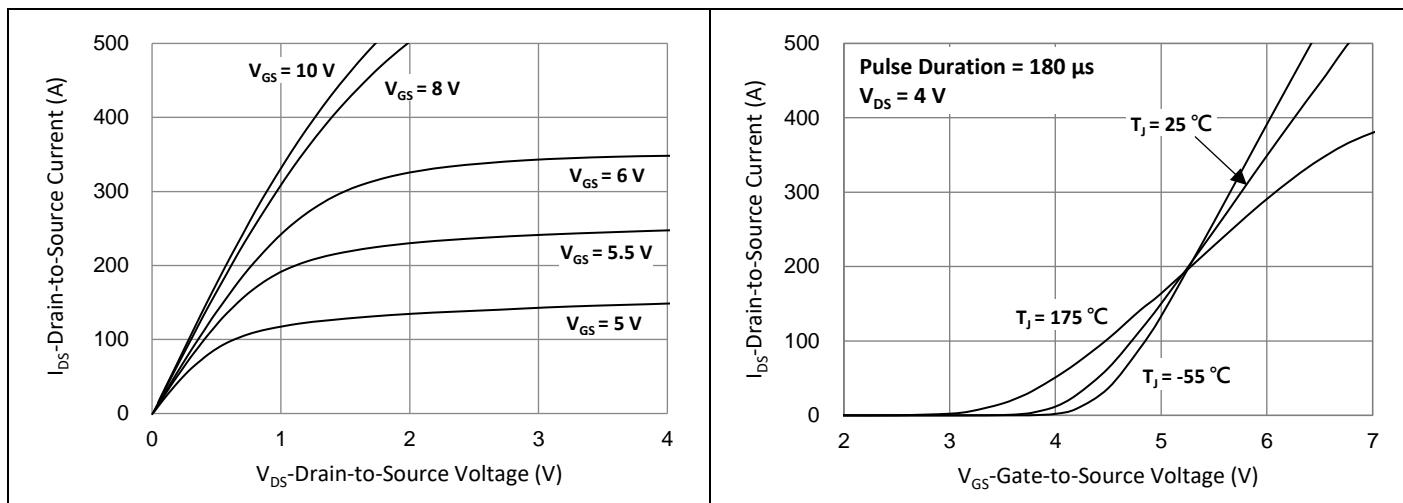


Fig.1 Output Characteristics

Fig.2 Transfer Characteristics

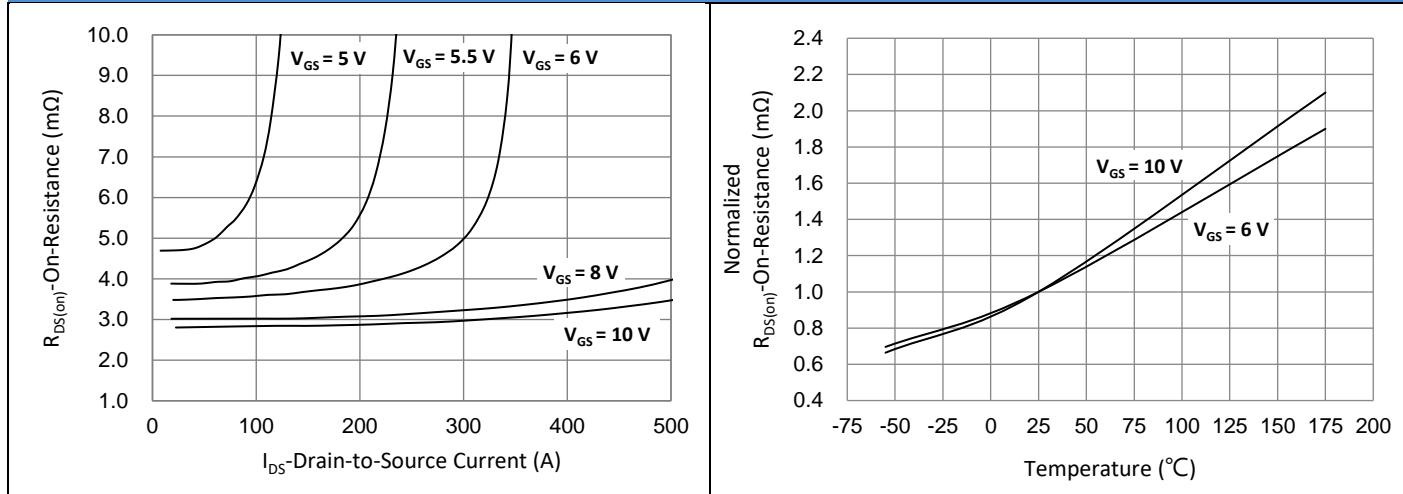


Fig.3 On-Resistance vs. Drain Current

Fig.4 On-Resistance vs. Junction temperature

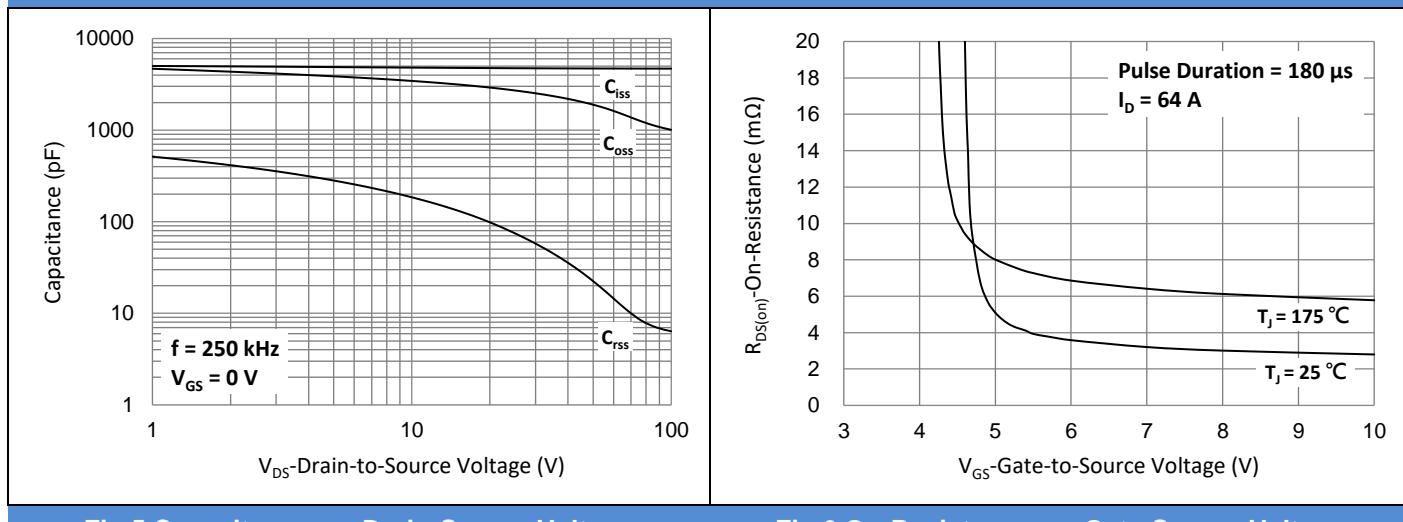
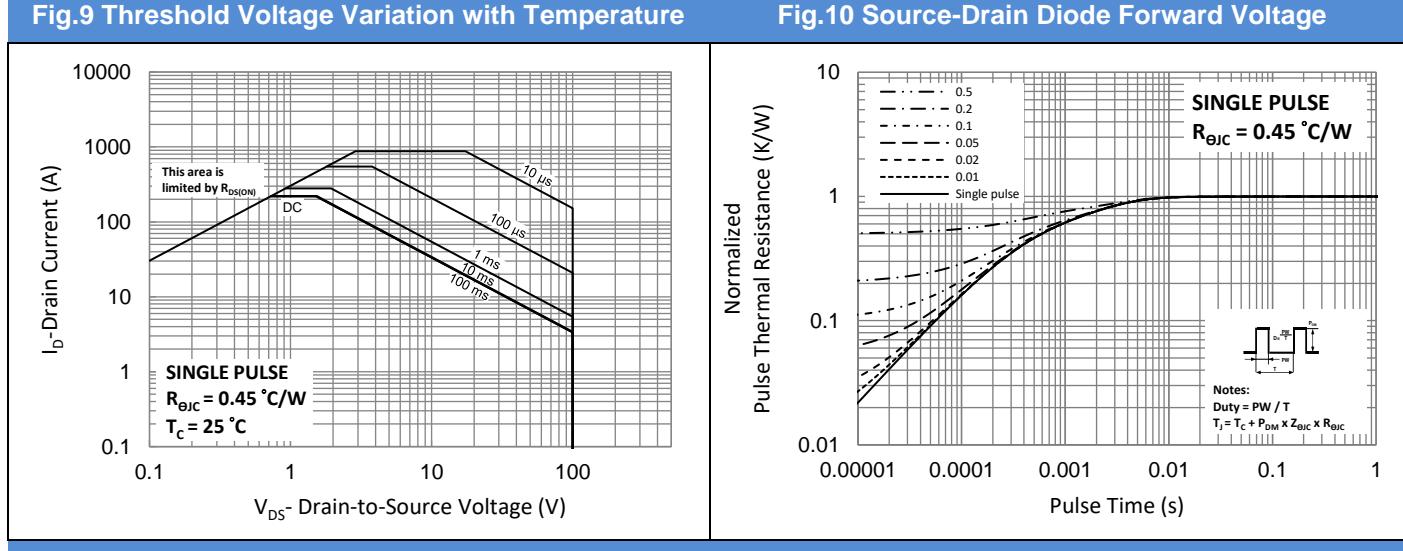
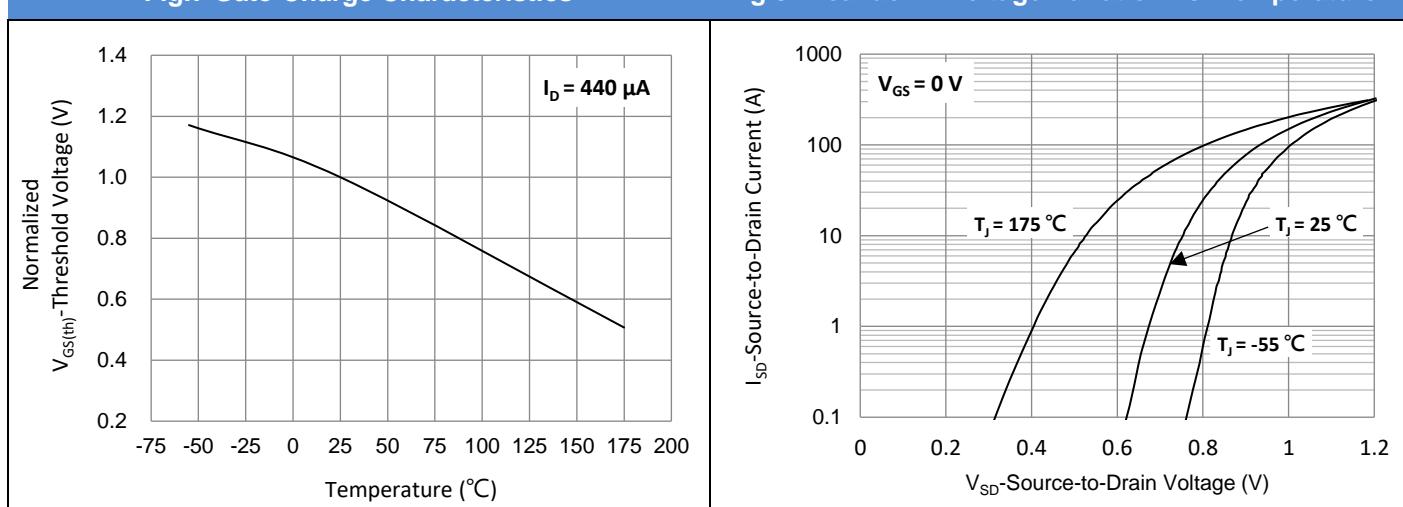
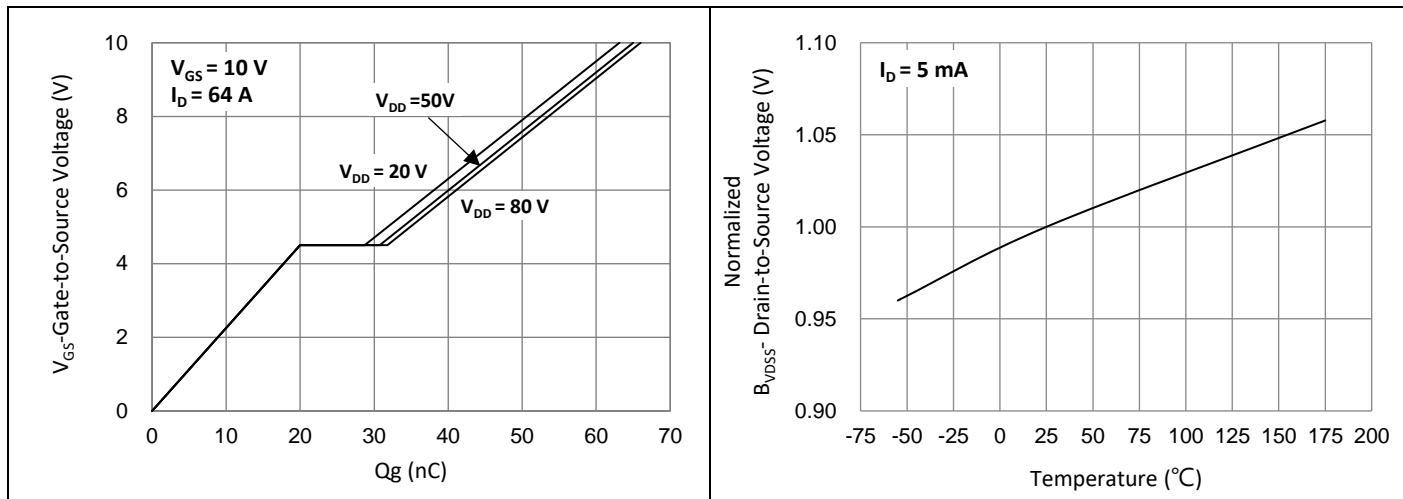


Fig.5 Capacitance vs. Drain-Source Voltage

Fig.6 On-Resistance vs. Gate-Source Voltage

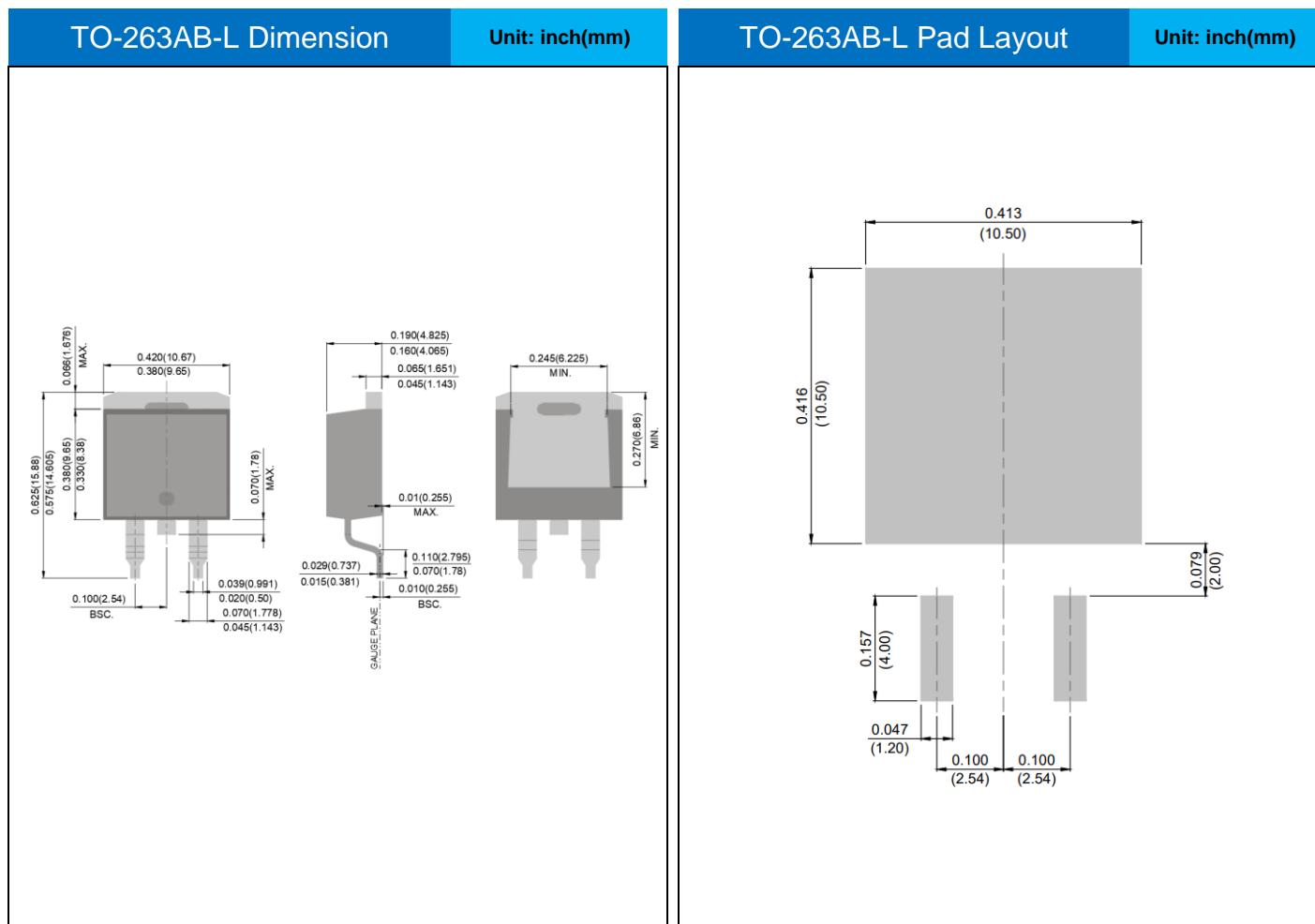
TYPICAL CHARACTERISTIC CURVES



Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PSMB033N10NS2	TO-263AB-L	800pcs / Reel	033N10NS

Packaging Information & Mounting Pad Layout



Marking Diagram

PJ
033N10NS
YWLL X

Y = Year Code
W = Week Code (A~Z)
LL = Lot Code (00~99)
x = Production Line Code

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